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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete if Known	
				Application Number	09/726,337
				Filing Date	December 1, 2000
				First Named Inventor	Hongyong ZHANG et al.
				Group Art Unit	2154
				Examiner Name	Unassigned
				Attorney Docket Number	0756-2228

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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
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				Filing Date	December 1, 2000
				First Named Inventor	Hongyong Zhang et al
				Group Art Unit	2823
				Examiner Name	W. Fahmy
Sheet	1	of	4	Attorney Docket Number	0756-2228

U.S. PATENT DOCUMENTS						
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
00		5,403,772		04/04/1995	Zhang et al	
00		5,147,826		09/15/1992	Liu et al	
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00		Jp	02-140915 A		Oka	05/30/1990	Abstract
00		Jp	63-295065			11/1998	X
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00		Jp	01-152719			06/15/1989	Abstract
00		EPO	0 480 178			04/15/1992	X

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				Group Art Unit	2823
				Examiner Name	W. Fahmy
Sheet	2	of	4	Attorney Docket Number	0756-2228

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		"Selective Area Crystalline of Amorphous Silicon Films By Low-Temperature Rapid Thermal Annealing", Appl. Phys. Lett., Vol. 55, No. 17, August 14, 1989.	
		C. Hayzelden et al., "In Situ Transmission Electron Microscopy Studies of Silicide-Mediated Crystallization of Amorphous Silicon" (3 pages)	
		A.V. Dvurechenskii et al., "Transport Phenomena in Amorphous Silicon Doped by Ion Implantation of 3d Metals", <u>Akademikian Lavrentev Prospekt</u> 13, 630090 Novosibirsk 90, USSR, pp. 635-640.	
		T. Hempel et al., "Needle-Like Crystallization of Ni Doped Amorphous Silicon Thin Films", <u>Solid State Communications</u> , Vol. 85, No. 11, pp. 921-924, 1993.	
		"Crystallized Si Films By Low-Temperature Rapid Thermal Annealing of Amorphous Silicon", R. Kakkad, J. Smith, W.S. Lau, S.J. Fonash, J. Appl. Phys. 65 (5), March 1, 1989, 1989 American Institute of Physics, p. 2069-2072	
		"Polycrystalline Silicon Thin Film Transistors on Corning 7059 Glass Substrates Using Short Time, Low Temperature Processing", G. Liu, S.J. Fonash, Appl. Phys. Lett. 62 (20), May 17, 1993, 1993 American Institute of Physics, p. 2554-2556	
		"Selective Area Crystallization of Amorphous Silicon Films by Low-Temperature Rapid Thermal Annealing", Gang Liu and S.J. Fonash, Appl. Phys. Lett 55 (7), August 14, 1989, 1989 American Institute of Physics, p. 660-662	
		"Low Temperature Selective Crystallization of Amorphous Silicon", R. Kakkad, G. Liu, S.J. Fonash, Journal of Non-Crystalline Solids, Volume 115, (1989), p. 66-68	
		Gross et al., "Laser direct-write metallization in thin palladium films, Journal of Applied Physics, pp. 1628-1632.	

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		"Laser Direct-Write Metallization in Thin Palladium Acetate Films", M.E. Gross et al., J. Appl. Phys. 64(4), 2/15/1987	
		"In Situ Transmission Electron Microscopy Studies of Silicide-Mediated Crystallization of Amorphous Silicon", Hayzelden et al. (3 pages), October 1991	
		Transport Phenomena in Amorphous Silicon Doped By Ion Implantation of 3d Metals", A.V. Dvurechenskii et al., Akademikian Lavrentev Prospekt 13, 530090 Novosibirsk 90, USSR, pp. 635-640, 1986.	
		"Needle-Like Crystallization of Ni Doped Amorphous Silicon Thin Films", Hempel, et al. Solid State Communications, Volume 85, No. 11, pp. 921-924, March 1983.	
		"Polycrystalline Silicon Thin Film Transistors On Corning 7059 Glass Substrates Using Short Time, Low-Temperature Processing", Appl. Phys. Lett. Vol. 62, No. 20 May 17, 1993	

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